NSN 5961-00-237-3341

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-237-3341 **Inclosure Material:** Metal **Overall Length:** 0.417 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 150.0 off-state voltage, rms total **Current Rating Per Characteristic:** 10.00 amperes drain current nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 105.0 degrees celsius case **Special Features:** 3 terminals, threaded stud and solderless lug **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0